

Comparing Nonlinear Vector Network Analyzer Methodologies

Steve Dudkiewicz, Gary Simpson and Giampiero Esposito

Maury Microwave Corp., Ontario, Calif.

Mauro Marchetti

Anteverta-mw, Delft, The Netherlands

Marc Vanden Bossche

National Instruments, Austin, Texas

Scattering parameters (S-parameters) were first mentioned in articles and textbooks in the 1950s and 1960s by Matthews, Collins and Kurokawa and popularized by the release of Hewlett Packard's first network analyzers in the 1960s. Since then, S-parameters have been used to describe the complex characteristics of a network by quantifying the RF power flowing between its ports. S-parameters are essentially the ratio of the reflected and transmitted signal at a given port to the incident signal at a given port under perfect match conditions (see **Figure 1**). When referring to a transistor, these parameters can be used to calculate return loss, gain and isolation.¹

It is important to understand that S-parameters are only truly valid for linear networks, where the characteristics of the network are independent of the level of the signal being driven into the network. When considering a semiconductor application such as a transistor, this refers to its small-signal operating condition, in which the input drive power does not affect the S-parameters of the transistor. Under small-signal operating conditions, a transistor will have linear gain at the fundamental drive frequency and not excite additional powers at the harmonic frequencies. Linear operation of a transistor and the associated input and output waveforms are shown in **Figure 2**.

The question arises how to thoroughly describe and model a transistor operating under nonlinear large-signal conditions. These conditions occur commonly for high power and high efficiency power amplifiers operating in advanced classes of operation. Under these operating conditions, powers are induced at harmonic frequencies when excited by a sine wave, and in-band and out-of-band modulation products are created under modulation excitation. Considering a simple sine wave excitation, a transistor's characteristics are dependent on the level of the input drive signal, shown in both frequency and time domains in **Figure 3**.

When the transistor is in deep compression and its output is composed of multiple harmonics, the device behavior cannot be described correctly by S-parameters, which are frequency domain quantities. It is much more natural to analyze the behavior of the device under test (DUT) in terms of time domain RF voltage and current waveforms. Clear evidence of this is provided by the theoretical description of the different modes of operation of power amplifiers, which is completely done in time domain. In this case, a nonlinear vector network analyzer (NVNA) can be used to measure the incident and reflected a- and b-waves at the transistor input and output, in both amplitude and phase. The data can then reconstruct the time

domain RF voltage and current waveforms and RF load lines as well as all the conventional performance parameters of the device, such as input and output power, gain and efficiency.²

Several commercial solutions exist to measure nonlinear transistor performance. This article will compare Maury Microwave's MT4463 large signal network analyzer (LSNA) and the MT2000 mixed-signal active load-pull system (MSALP). The MT4463 LSNA was offered in conjunction with Agilent's Network Measurement and Description Group between 2003 and 2008. The MT2000 is currently offered as an integrated non-50 Ω measurement system, in conjunction with Anteverta-mw.

MT4463 LARGE SIGNAL NETWORK ANALYZER

The LSNA concept was first introduced in the 1980s by researchers using oscilloscopes to measure voltage and current waveforms at the gate and drain of a transistor. Research continued through the late 1980s and early 1990s with the goal of improving the capabilities of the technique. The breakthrough that led to the commercialization of the LSNA product occurred in 1994 with the release of the Hewlett Packard (HP) microwave transition analyzer (MTA). In 1996, HP designed the nonlinear network measurement system (NNMS), the precursor to the first LSNA, which was commercialized in 2003 by Maury Microwave.

The goal of the LSNA is to measure the wideband incident and reflected waves of a DUT at fundamental and harmonic frequencies using a periodic CW or periodically modulated signal, as shown in **Figure 4**. The injection signal is external to the core measurement instruments and, depending on the model selected, can be used to synthesize single-tone CW, pulsed CW or periodically modulated signals (i.e., multi-tone).

The hardware architecture of the LSNA is shown in **Figure 5**. The DUT has an associated input and output signal which can be represented by waves. The LSNA test set separates the incident and reflected waves into four measurement channels. A harmonic-sampler coherently down-converts the carrier and the harmonic and modulation frequencies to IF. A

14-bit digitizer and digital signal processor provides the raw signal data, and a computer performs error correction to represent the incident and reflected waves in the reference plane at the DUT. Additional software can plot the data in multiple formats (A/B, V/I, time, frequency or envelope).

The enabling technology of the LSNA lies in the HP MTA and its sampler-based technology, or sampling converter, as shown in **Figure 6**. With a sampler, all frequencies are acquired in the same measurement using a fixed LO, including the fundamental, harmonics, modulation and intermodulation frequencies.

In the default configuration, the LSNA is terminated with 50 Ω . Non-50 Ω measurements are enabled with the addition of passive or active tuners. Referring to Figure 1, the reflection coefficient Γ_L presented to the DUT is the ratio a_2/b_2 , where a_2 is the "reflected" wave and b_2 is the DUT's transmitted power. In order to tune the impedance presented to a DUT, the signal a_2 must be manipulated such that $\Gamma_L = a_2/b_2$ is solved.

Passive mechanical tuners may be used to vary the impedance presented to the DUT. A passive slide-screw tuner (see **Figure 7**) consists of a precision 50 Ω slab line, with two parallel plates and a center conductor, and a metallic probe (or slug). When the probe is completely withdrawn from the slab line, the signal entering the tuner passes through with minimal interference, resulting in a low a_2 signal. As the probe is lowered into the slab line, the electric field of the signal is interrupted, part of the signal is reflected back towards the DUT, and the a_2 signal increases. As the probe's horizontal position changes, the distance between the tuning element (probe) and the DUT changes, changing the phase of the reflection. By moving the probe up and down, left and right, nearly any impedance can be presented to the DUT, represented by full coverage of the Smith Chart (see **Figure 8**).

With open loop active load-pull, instead of using a passive tuner to reflect the signal back towards the DUT to manipulate a_2 , the signal is terminated, and a new signal a_2 is introduced back towards the DUT. In this manner, the magnitude of reflection can be as large as the new a_2 signal allows

– even outside the Smith Chart – and created at the fundamental and harmonic frequencies.

One advantage of sampler-based measurements is speed, since the signal across the entire frequency spectrum is captured at once. Another advantage is signal type, since any periodic signal can be sampled. A disadvantage of sampler-based measurements is dynamic range, which is typically limited to approximately 60 to 70 dBc. The LSNA has been designed as a network analyzer using wideband receivers to measure vector corrected incident and reflected waves, allowing different types of external stimuli, including tuners, to be configured depending on the application. Therefore, external synthesizers are needed to create the injection signals to complete the network analyzer architecture. Also, any non-50 Ω analysis requires additional tuning networks, such as passive or active tuners. Passive tuners can be used with any injected signal, however they provide a wideband response which can distort wideband signals and degrade measurement results. Open loop active load-pull can be used with CW or pulsed-CW signals only.

The MT4463 LSNA covered two frequency ranges, 0.6 to 20 GHz or 0.6 to 50 GHz. The IF bandwidth was 10 MHz, RF frequency resolution was 1 kHz and the measurement dynamic range was 60 to 70 dB.³ Additional signal sources were necessary for multi tone or modulated signal synthesis, and passive or active tuners were needed for load-pull measurements.

MT2000 MIXED-SIGNAL ACTIVE LOAD-PULL SYSTEM

The MT2000 MSALP is a NVNA with integrated wideband sources (two, four or six) that is capable of measuring a- and b-vector waves and S-parameters and with inherent wideband impedance control capabilities. The MT2000 covers between 300 MHz and 40 GHz, with 2, 4 or 6 active tuning loops, modulation bandwidths up to 240 MHz and a measurement dynamic range of 80 dB.⁴

The hardware architecture of the system is shown in **Figure 9**. Wideband arbitrary waveform generators (AWG) are used to create a wideband signal around baseband, which is then up-converted in the RF test set. The

RF test set consists of local oscillators (LO) combined with I/Q mixers to up-convert the baseband signal to the fundamental and harmonic RF frequencies and inject source and load I/Q signals into the DUT. The resulting RF signal output is then down-converted back to baseband, and its a- and b-waves are analyzed by wideband analog-to-digital converters (ADC). Because both the AWGs and ADCs are wideband, a signal with up to 240 MHz of bandwidth can be generated and analyzed.

To generate a wideband signal, a repetitive time domain modulated signal, compliant with industry standards, is generated and then analyzed in the frequency domain. The signal is composed of thousands of tones, as shown in **Figure 10**. The wideband signal is up-converted and injected into the DUT as a_1 . The resulting output signal b_2 consists of a modified version of the original signal, including an amplified signal at the fundamental frequency (with the possibility of signal distortion if modulated) and signals at the harmonic and baseband frequencies. Because the device may not be physically matched at the input, part of the signal may be reflected as b_1 . The signal flow is shown in **Figure 11**.

Wideband impedance load-pull (see **Figure 12**) is achieved by varying a_2 at Hz tone spacing to satisfy $\Gamma_L = a_2/b_2$ throughout the wideband signal. The wideband AWGs are used to create the pre-distorted CW, pulsed CW or modulated a_2 signal at baseband, so the up-converted signal fulfills the desired wideband impedance grid at the fundamental and harmonic frequencies. The same technique can be used on the input to adjust the source impedances presented wideband at the fundamental and harmonic frequencies.

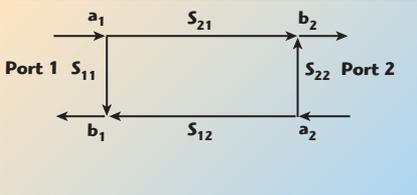
The wideband signal generation and analysis can also be used with single tone signals where the signal is divided in time. The record containing the wave modulation for a single modulated impedance can contain several wave magnitudes and phases representing many single tone impedances. **Figure 13** shows an example of time slotting. In this manner, it is possible to load-pull 1000 impedance/power states per minute.

CONCLUSION

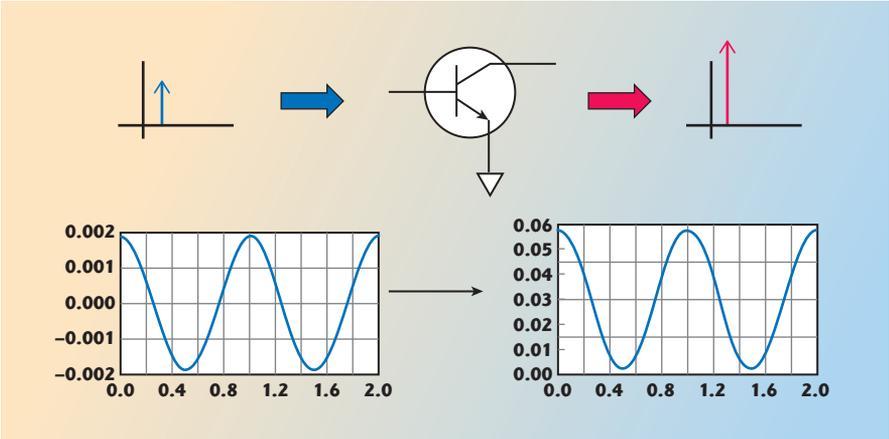
NVNA is a powerful tool to investigate, characterize and model transistor technologies operating under nonlinear conditions. Several commercial solutions offer NVNA capabilities, built around sampler or mixer technologies and each with their own advantages and limitations. A comparison of the two NVNA methodologies discussed in this article is in **Table 1**. In determining which approach to use, consider the type of injection signal required (CW, pulsed CW, single-tone, multi-tone or modulated), the level of measurement dynamic range, measurement speed, impedance control methodology (passive, narrowband active or wideband active), impedance control speed and system availability and support. It is clear that as measurement and signal-processing technologies evolve, newer solutions are overcoming the limitations of the past. ■

References

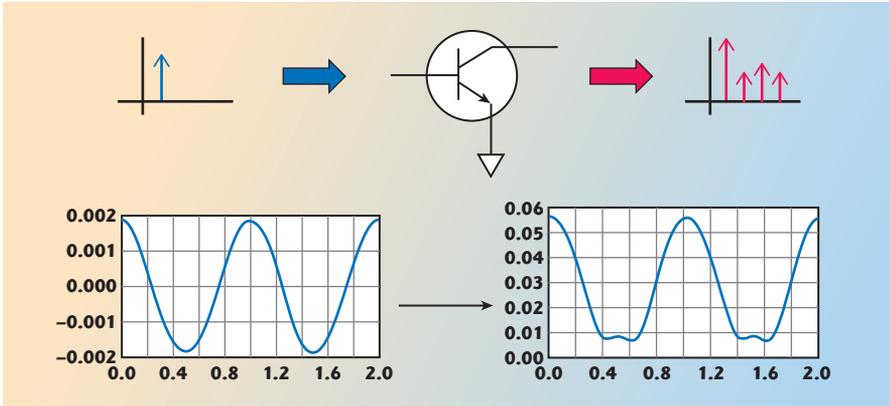
1. D. M. Pozar, "Microwave Engineering," John Wiley, New York, 2005.
2. J. Verspecht, "Large Signal Network Analysis – Going Beyond S-Parameters," ARFTG Microwave Measurement Conference short course notes, 2003.
3. Maury Microwave, Data Sheet 4T-090, MT4463 Large Signal Network Analyzer (LSNA).
4. Maury Microwave, Data Sheet 4T-095, MT2000 Mixed Signal Active Load Pull system (MSALP).



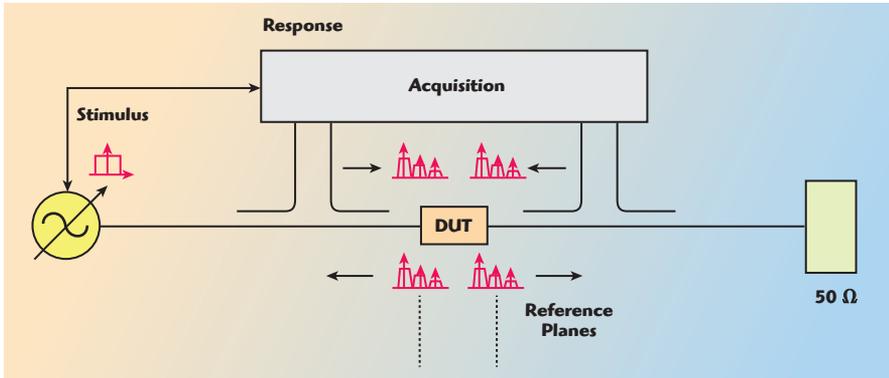
▲ Fig. 1 Generalized two-port network.



▲ Fig. 2 Linear operation of a transistor.

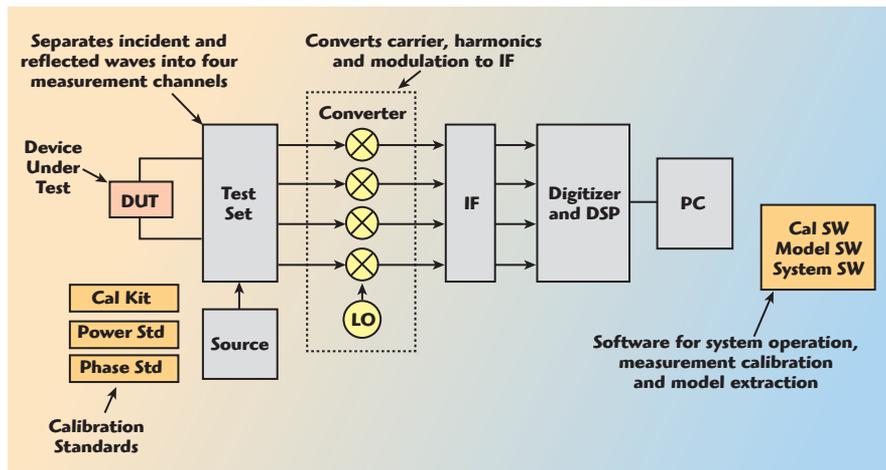


▲ Fig. 3 Nonlinear operation of a transistor.

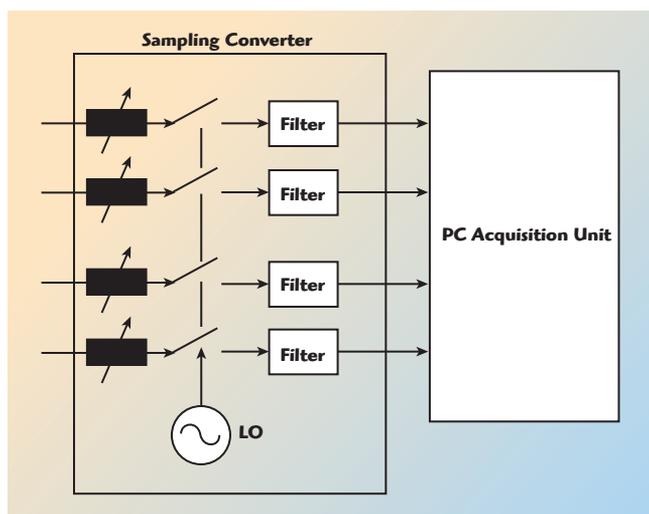


▲ Fig. 4 Signal flow of LSNA with exemplary 50 ohm termination.

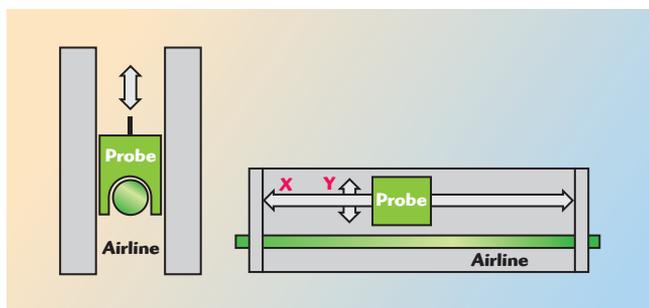
ApplicationNote



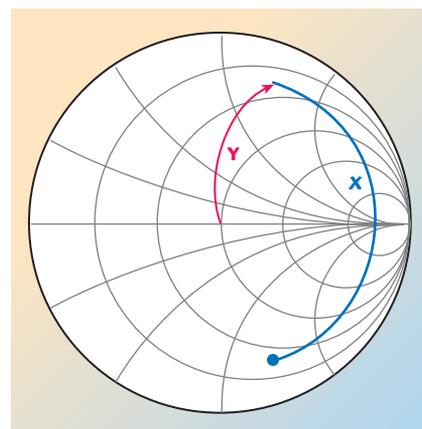
▲ Fig. 5 Functional block diagram of the LSNA.



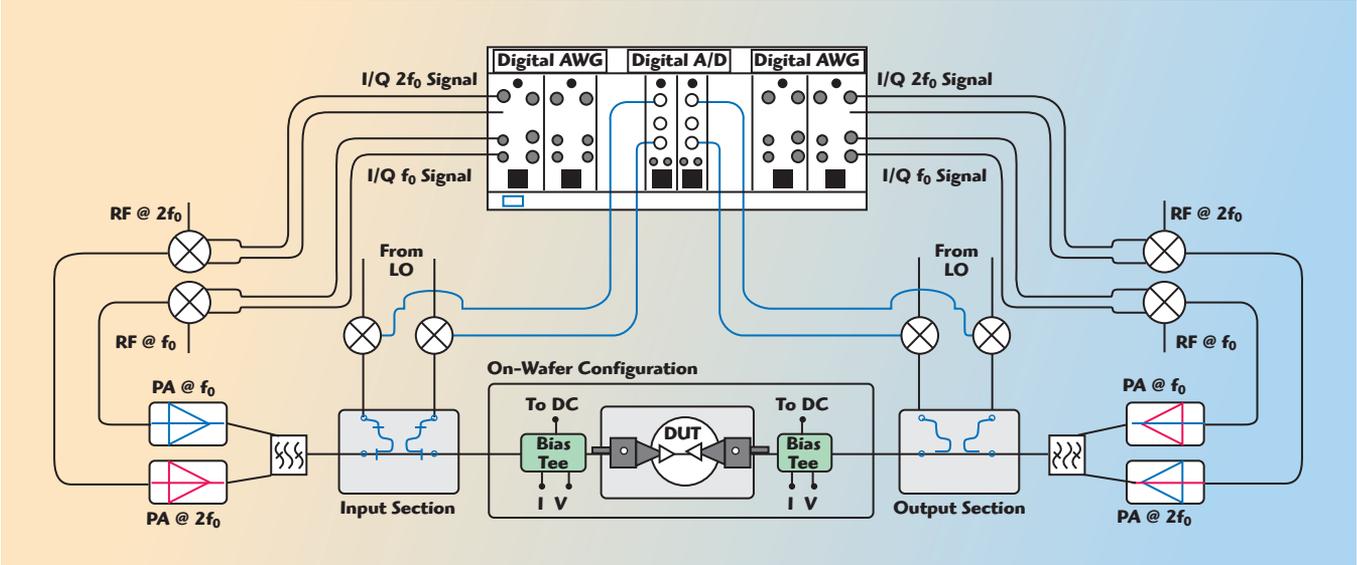
▲ Fig. 6 LSNA sampling converter.



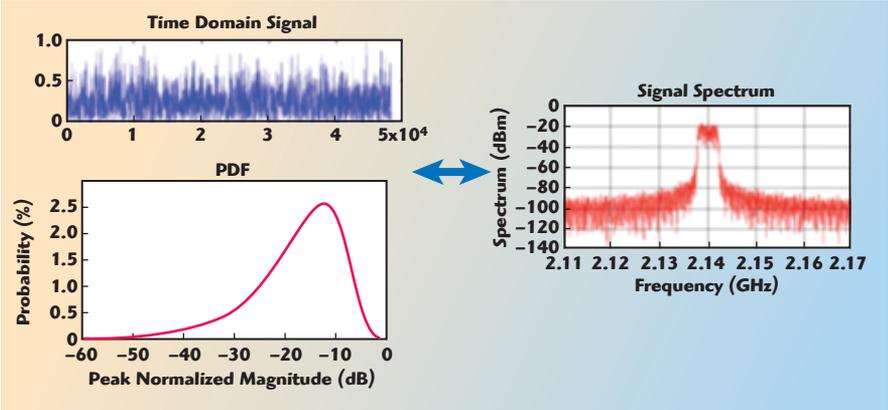
▲ Fig. 7 Cross section and side view of the tuner, slab line and probe.



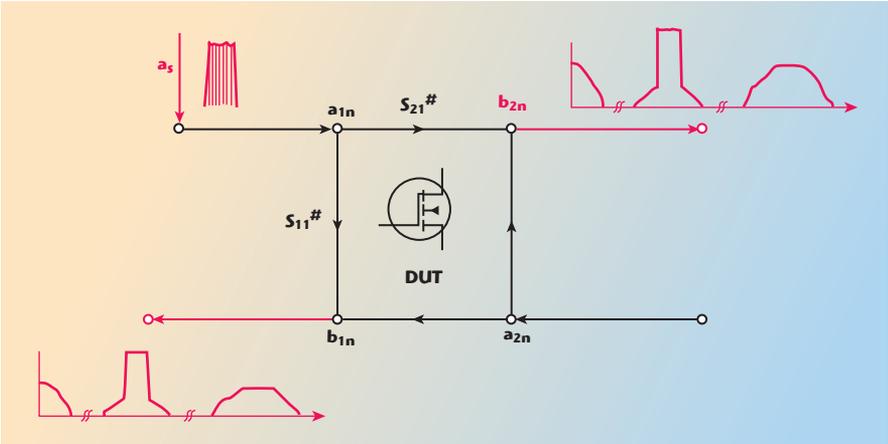
▲ Fig. 8 Impedance change by varying the horizontal (X) and vertical (Y) probe position.



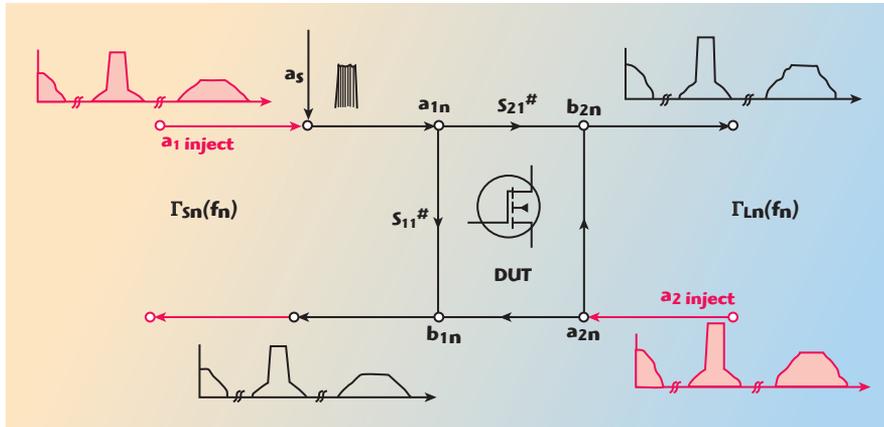
▲ Fig. 9 Functional block diagram of the MT2000.



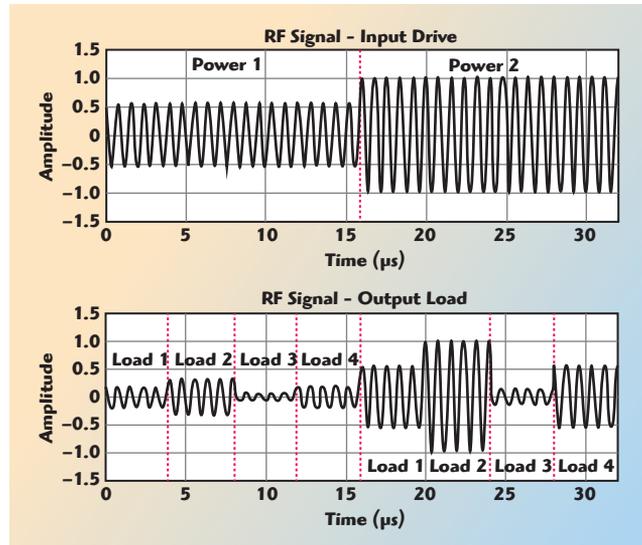
▲ Fig. 10 Realistic wideband signal.



▲ Fig. 11 Signal flow of the original injected signal, reflected signal and amplified signal.



▲ Fig. 12 Signal flow of the original injected signal, reflected signal and amplified signal (black) and the generated signals for active tuning (red).



▲ Fig. 13 Time slotting of a CW signal for fast load-pull measurements.

TABLE 1 COMPARISON OF LSNA AND MSALP		
	<i>Advantage</i>	<i>Limitation</i>
MT4463 Large Signal Network Analyzer (LSNA)	<ul style="list-style-type: none"> • Sampler-Based Results in Faster Measurements • Waveform Reconstruction of Modulated Signal • Flexibility Quasi-Open Source Code 	<ul style="list-style-type: none"> • Modulation Bandwidth Limited to 10 MHz • No Wideband Impedance Control • Dynamic Range Limited to 60 to 70 dB • External Sources Required • External Impedance Tuning Required • Discontinued Platform
	<i>Advantage</i>	<i>Limitation</i>
MT2000 Mixed-Signal Active Load-Pull System (MSALP)	<ul style="list-style-type: none"> • 80 dB Dynamic Range • 240 MHz of Modulation Bandwidth (Plans for Higher Bandwidths in Future) • Internal Sources • Wideband Impedance Control for Modulated Signals • Fast Impedance Tuning (1000 Impedance/Power States per Minute in CW or Pulsed-CW) • Actively Supported and Expanded 	<ul style="list-style-type: none"> • No Waveform Reconstruction of Modulated Signals